

LEAD-FREE / RoHS-COMPLIANT HIGH POWER BIAS TEE

The BTN1-0040 is constructed using a custom-made, resonance-free conical inductor to achieve extremely broadband performance. By minimizing the overall inductor size and using proprietary packaging techniques, the BTN1-0040 is a superior option in terms of performance, reliability and ease-of-use when compared to cumbersome user-designed bias tees employing off-the-shelf conical inductors. The extremely low cutoff and resonance free operation makes the BTN1-0040 suitable for biasing amplifiers, lasers, and modulators driven with high frequency data patterns.





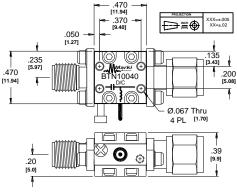
Features

- Broadband: 500 kHz to 40 GHz
- Low Insertion Loss
- High Power
- Non-Resonant
- Compact Size

Electrical Specifications - Specifications guaranteed from -55 to +100°C, measured in a 50Ω system.

Parameter	Frequency Range	Min	Тур	Мах
Insertion Loss (dB)	4 MHz-40 GHz		1.5	2.2
	500 kHz-4 MHz		2	
DC Port Isolation (dB)	500 kHz -1 GHz		50	
	1-40 GHz		30	
Return Loss (dB)			13	
RF Power (W)	500 kHz-40 GHz			10
DC Current (A)				1
DC Voltage (V)				50
DC Resistance (Ω)			0.5	
Inductance (uH)			22	
Capacitance (nF)			100	
Weight (g)			10	
Risetime /Falltime (ps) ¹			10	

¹Specified as 90%/10%. Calculated from $\tau_{bt}^2 = (\tau_{out}^2 - \tau_{in}^2)$



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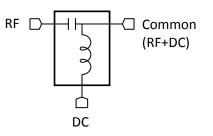


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Schematic



Application Examples

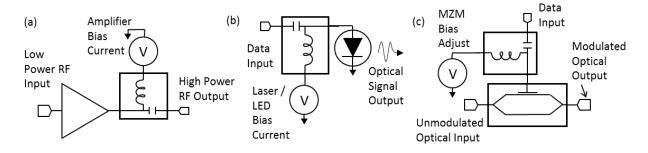
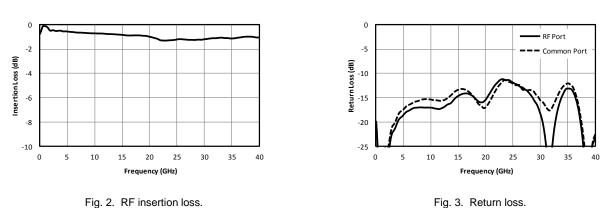


Fig. 1. Example Schematics of a) Broadband Microwave Amplifier Biasing, b) Laser/LED Biasing for Data Communication and c) Mach-Zender Modulator Biasing for Data Communication



Typical Performance

Fig. 3. Return loss.

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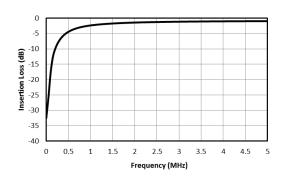
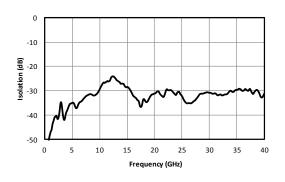


Fig. 4. Low frequency RF response.





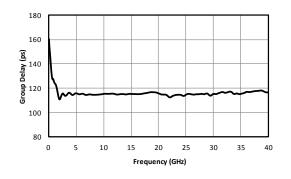


Fig. 8. Group delay.

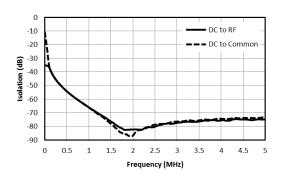
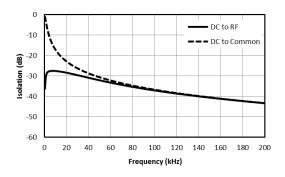


Fig. 5. Low frequency isolation.





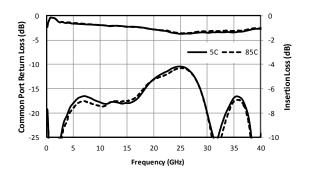


Fig. 9. Performance over temperature

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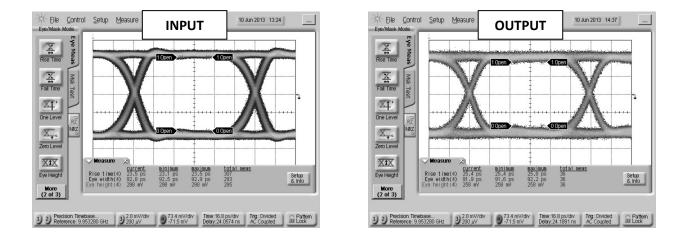


Fig. 10. Oscilloscope measurements of the BTN1-0040 with a 10Gb/s PRBS pattern. Eye diagrams are taken with a 2³¹-1 PRBS input demonstrating minimal eye distortion/closure afforded by the extremely low frequency operation of the bias tee.

Model Number	Description	
BTN1-0040	500 kHz to 40 GHz High Power Bias Tee	
	with 2.92 mm connectors ¹ , LEAD-FREE/RoHS COMPLIANT	

¹Consult factory for other connector options.

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Revision History

Revision code	Revision Date	Comment
В	May 2020	RoHS Compliant Assembly